imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

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BAS19L, BAS20L, BAS21L, BAS21DW5

High Voltage Switching Diode

Features

- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant
- S and NSV Prefixes for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

MAXIMUM RATINGS

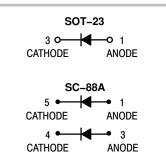
Rating	Symbol	Value	Unit
Continuous Reverse Voltage BAS19 BAS20 BAS21	V _R	120 200 250	Vdc
Repetitive Peak Reverse Voltage BAS19 BAS20 BAS21	V _{RRM}	120 200 250	Vdc
Continuous Forward Current	١ _F	200	mAdc
Peak Forward Surge Current (1/2 Cycle, Sine Wave, 60 Hz)	I _{FSM}	2	A
Repetitive Peak Forward Current (Pulse Train: T_{ON} = 1 s, T_{OFF} = 0.5 s)	I _{FRM}	0.6	A
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C
Power Dissipation (Note 1)	PD	385	mW
Electrostatic Discharge	ESD	HM < 500	V
		MM < 400	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. Mounted on FR-5 Board = $1.0 \times 0.75 \times 0.062$ in. ON

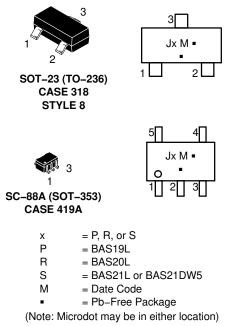
ON Semiconductor®

www.onsemi.com

HIGH VOLTAGE SWITCHING DIODE



MARKING DIAGRAMS



*Date Code orientation and/or overbar may vary depending upon the manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

BAS19L, BAS20L, BAS21L, BAS21DW5

THERMAL CHARACTERISTICS (SOT-23)

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board (Note 2)	P _D	225	mW
T _A = 25°C Derate above 25°C		1.8	mW/°C
Thermal Resistance Junction-to-Ambient (SOT-23)	$R_{ heta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate (Note 3)	PD	300	mW
T _A = 25°C Derate above 25°C		2.4	mW/°C
Thermal Resistance Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	–55 to +150	°C

THERMAL CHARACTERISTICS (SC-88A)

Characteristic	Symbol	Мах	Unit
Power Dissipation (Note 4)	PD	385	mW
Thermal Resistance – Junction–to–Ambient Derate Above 25°C	$R_{ heta JA}$	328 3.0	°C/W mW/°C
Maximum Junction Temperature	T _{Jmax}	150	°C
Operating Junction and Storage Temperature Range	T _J , T _{stg}	–55 to +150	°C

2. FR–5 = 1.0 \times 0.75 \times 0.062 in.

3. Alumina = $0.4 \times 0.3 \times 0.024$ in. 99.5% alumina.

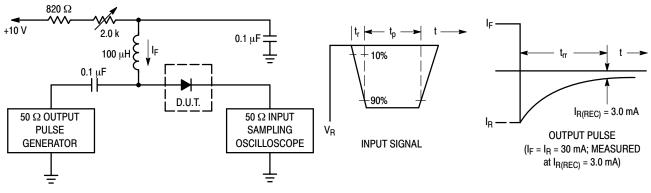
4. Mounted on FR-5 Board = $1.0 \times 0.75 \times 0.062$ in.

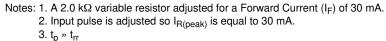
ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit	
Reverse Voltage Leakage Current		I _B			μAdc
(V _R = 100 Vdc)	BAS19		-	0.1	
$(V_{R} = 150 \text{ Vdc})$	BAS20		-	0.1	
(V _R = 200 Vdc)	BAS21		-	0.1	
(V _R = 100 Vdc, T _J = 150°C)	BAS19		-	100	
$(V_{R} = 150 \text{ Vdc}, T_{J} = 150^{\circ}\text{C})$	BAS20		-	100	
$(V_R = 200 \text{ Vdc}, T_J = 150^{\circ}\text{C})$	BAS21		-	100	
Reverse Breakdown Voltage		V _(BR)			Vdc
(I _{BR} = 100 μAdc)	BAS19	()	120	-	
(I _{BR} = 100 μAdc)	BAS20		200	-	
(I _{BR} = 100 μAdc)	BAS21		250	-	
Forward Voltage		VF			Vdc
(I _F = 100 mAdc)			-	1.0	
$(I_F = 200 \text{ mAdc})$			-	1.25	
Diode Capacitance ($V_R = 0$, f = 1.0 MHz)		CD	-	5.0	pF
Reverse Recovery Time ($I_F = I_R = 30$ mAdc, $I_{R(REC)} = 3$.0 mAdc, R _L = 100)	t _{rr}	-	50	ns

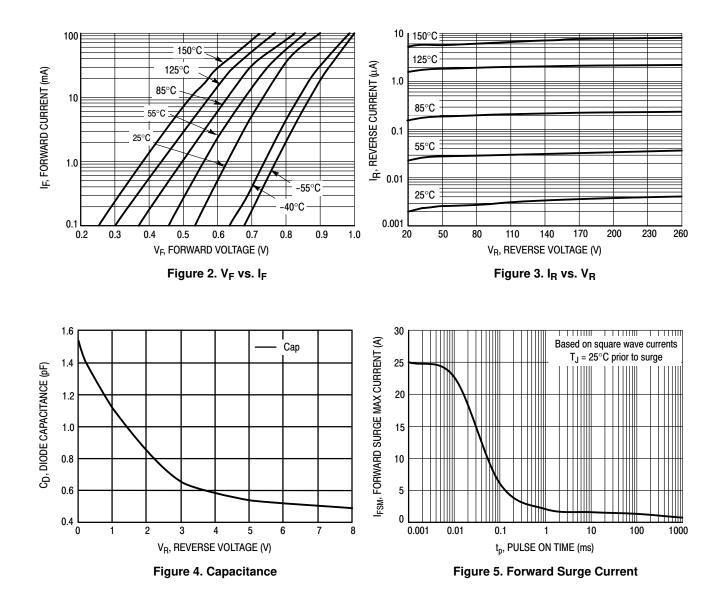
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

BAS19L, BAS20L, BAS21L, BAS21DW5









BAS19L, BAS20L, BAS21L, BAS21DW5

ORDERING INFORMATION

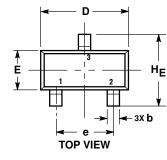
Device	Package	Shipping [†]		
BAS19LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel		
BAS19LT3G	SOT-23 (Pb-Free)	10000 / Tape & Reel		
NSVBAS19LT1G*	SOT-23 (Pb-Free)	3000 / Tape & Reel		
BAS20LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel		
BAS20LT3G	SOT-23 (Pb-Free)	10000 / Tape & Reel		
NSVBAS20LT3G*	SOT-23 (Pb-Free)	10000 / Tape & Reel		
SBAS20LT1G*	SOT-23 (Pb-Free)	3000 / Tape & Reel		
BAS21LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel		
SBAS21LT1G*	21LT1G* SOT-23 (Pb-Free)			
BAS21LT3G	SOT-23 (Pb-Free)	10000 / Tape & Reel		
SBAS21LT3G*	SOT-23 (Pb-Free)	10000 / Tape & Reel		
BAS21DW5T1G	SC–88A (Pb–Free)	3000 / Tape & Reel		
SBAS21DW5T1G*	SC-88A (Pb-Free)	3000 / Tape & Reel		
SBAS21DW5T3G*	SC-88A (Pb-Free)	10000 / Tape & Reel		

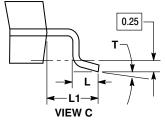
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
 *S and NSV Prefixes for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified

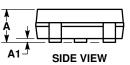
and PPAP Capable.

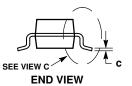
PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AR**









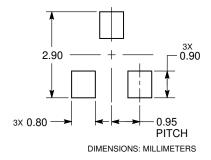
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH.
 MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF
 THE BASE MATERIAL.
 4. DIMENSIONS OF AND E DO NOT INCLUDE MOLD FLASH,
 PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
С	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
HE	2.10	2.40	2.64	0.083	0.094	0.104
Т	0°		10°	0°		10°

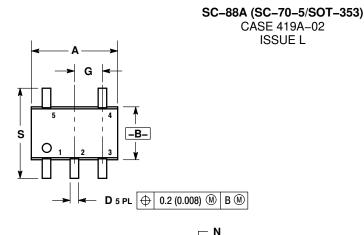
STYLE 8:

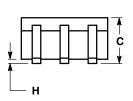
PIN 1. ANODE 2. NO CONNECTION 3. CATHODE

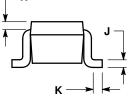
RECOMMENDED SOLDERING FOOTPRINT



PACKAGE DIMENSIONS







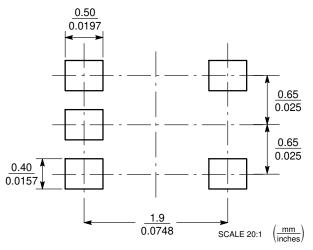
NOTES:

 DIES.
 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 419A-01 OBSOLETE. NEW STANDARD 3.

419A-02 DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE 4 BURRS.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
С	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026 BSC		0.65 BSC	
Н		0.004		0.10
ſ	0.004	0.010	0.10	0.25
Κ	0.004	0.012	0.10	0.30
Ν	0.008 REF		0.20	REF
s	0.079	0.087	2.00	2.20

SOLDER FOOTPRINT



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